

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

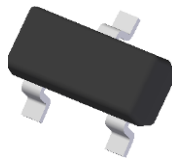
- $BV_{CEO} > 45V$
- $I_C = 0.5A$ Continuous Collector Current
- $I_{CM} = 1A$ Peak Pulse Current
- Complementary PNP Types: [BC807-16](#)
- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- For Switching and AF Amplifier Applications
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The AC817-40Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

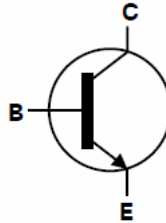
Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

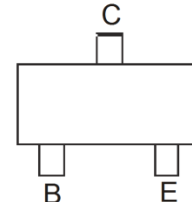
SOT23



Top View



Device Symbol



Top View
Pinout

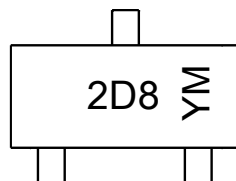
Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
AC817-40Q-7	SOT23	2D8	7	8	3,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information

SOT23



2D8 = Product Type Marking Code
YM = Date Code Marking
Y or \bar{Y} or \underline{Y} = Year (ex: M = 2025)
M = Month (ex: 9 = September)

Date Code Key

Year	2017	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	E	-	M	N	P	R	S	T	U	V	W	X

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EB0}	5.0	V
Collector Current	I _C	0.5	A
Peak Collector Current	I _{CM}	1.0	A
Peak Base Current	I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	310	mW
		350	
Thermal Resistance, Junction to Ambient	R _{θJA}	403	°C/W
		357	
Thermal Resistance, Junction to Leads	R _{θJL}	350	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:

5. For a device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single-sided 1oz copper; device is measured under still air conditions whilst operating in a steady state.
6. Same as Note 5, except mounted on 15mm x 15mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

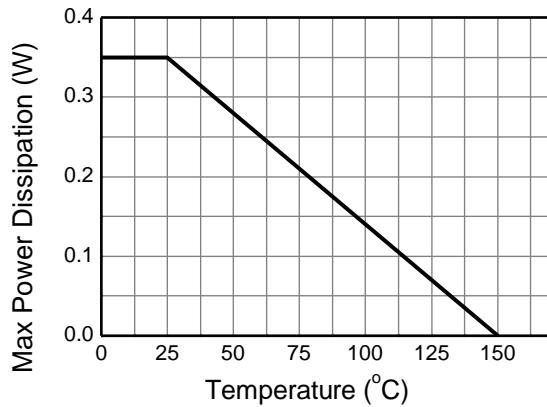


Figure 1. Derating Curve

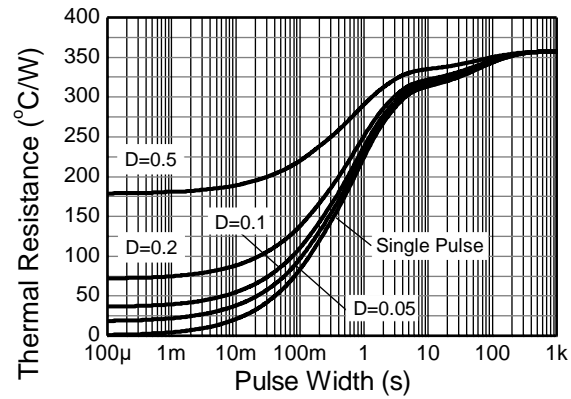


Figure 2. Transient Thermal Impedance

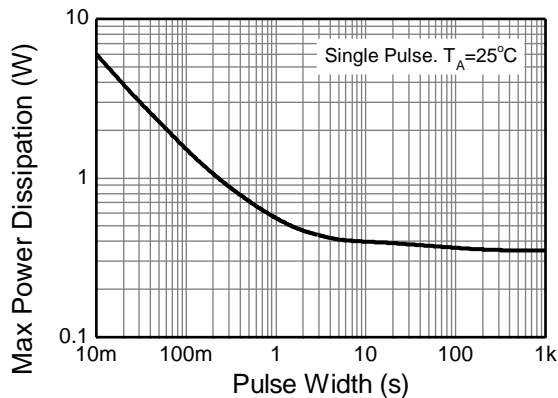


Figure 3. Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	45	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _C = 100μA
Collector-Emitter Cutoff Current	I _{CES}	—	—	100 5.0	nA μA	V _{CE} = 45V V _{CE} = 25V, T _J = +150°C
Emitter-Base Cutoff Current	I _{EBO}	—	—	100	nA	V _{EB} = 5.0V
DC Current Gain (Note 9)	h _{FE}	250 170	—	600 —	—	V _{CE} = 1.0V, I _C = 100mA V _{CE} = 1.0V, I _C = 300mA
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	—	0.7	V	I _C = 500mA, I _B = 50mA
Base-Emitter Voltage (Note 9)	V _{BE}	—	—	1.2	V	V _{CE} = 1.0V, I _C = 300mA
Gain Bandwidth Product	f _T	100	—	—	MHz	V _{CE} = 5.0V, I _C = 10mA f = 50MHz
Collector-Base Capacitance	C _{CBO}	—	—	12	pF	V _{CB} = 10V, f = 1.0MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

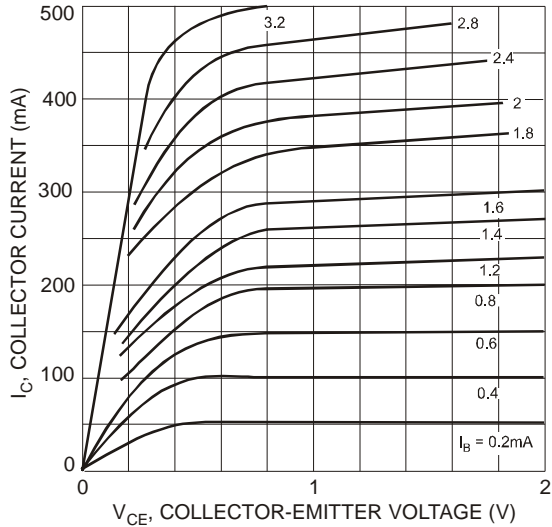


Figure 4. Typical Collector Current vs. Collector-Emitter Voltage

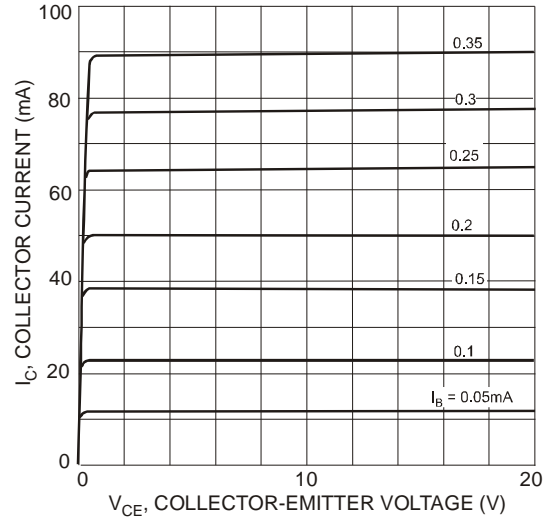


Figure 5. Typical Collector Current vs. Collector-Emitter Voltage

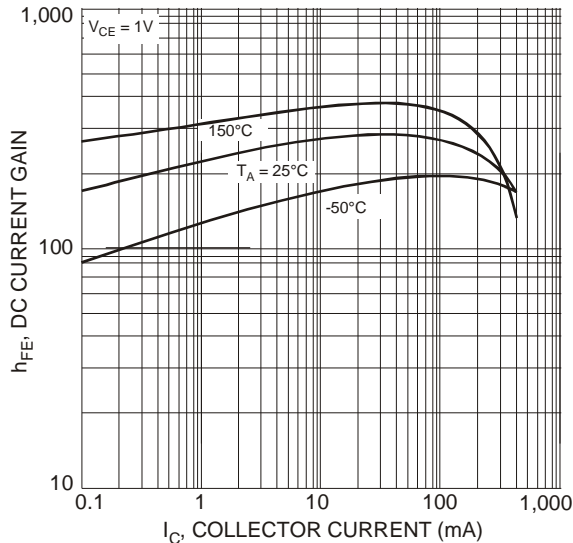


Figure 6. Typical DC Current Gain vs. Collector Current

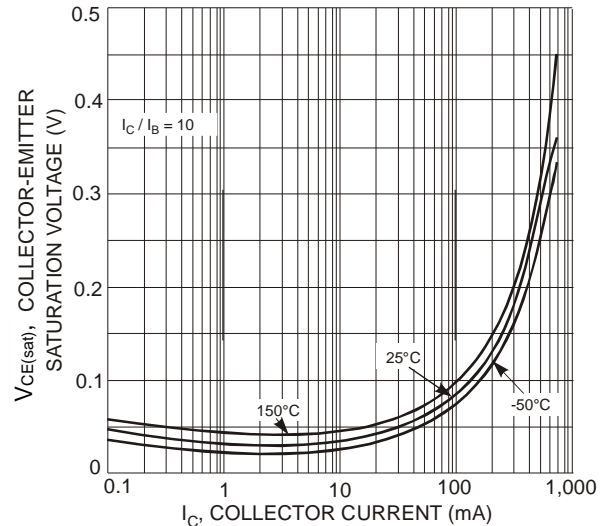


Figure 7. Typical Collector-Emitter Saturation Voltage vs. Collector Current

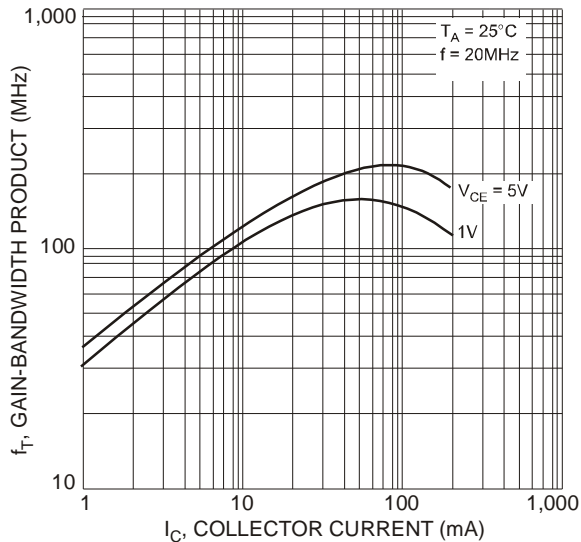
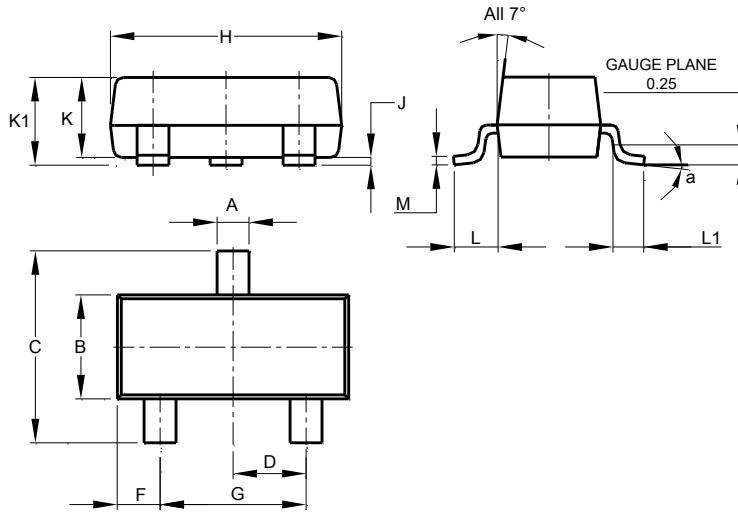


Figure 8. Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT23

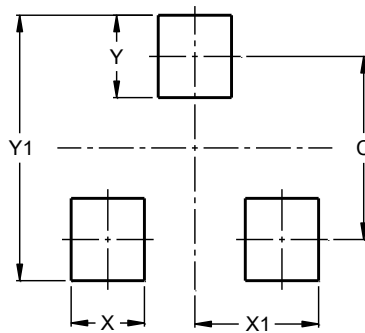


SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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